## MC74LVX374

## Octal D-Type Flip-Flop with 3-State Outputs

## With 5V-Tolerant Inputs

The MC74LVX374 is an advanced high speed CMOS octal D-type flip-flop with 3-state outputs. The inputs tolerate voltages up to 7.0 V , allowing the interface of 5.0 V systems to 3.0 V systems.

This 8-bit D-type flip-flop is controlled by a clock input and an output enable input. When the output enable input is high, the eight outputs are in a high impedance state.

## Features

- High Speed: $\mathrm{f}_{\max }=160 \mathrm{MHz}(\mathrm{Typ})$ at $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$
- Low Power Dissipation: $\mathrm{I}_{\mathrm{CC}}=4 \mu \mathrm{~A}$ (Max) at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Low Noise: V ${ }_{\text {OLP }}=0.8 \mathrm{~V}$ (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance:

Human Body Model > 2000 V;
Machine Model > 200 V

- These Devices are $\mathrm{Pb}-$ Free and are RoHS Compliant

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SOIC-20 DW SUFFIX
CASE 751D
TSSOP-20
DT SUFFIX
CASE 948E

## PIN ASSIGNMENT



MARKING DIAGRAMS


SOIC-20


TSSOP-20

LVX374 = Specific Device Code
A = Assembly Location
WL, L = Wafer Lot
$Y \quad=$ Year
WW, W = Work Week
G or • = Pb-Free Package
(Note: Microdot may be in either location)

## PIN NAMES

| Pins | Function |
| :--- | :--- |
| $\overline{\text { OE }}$ | Output Enable Input |
| CP | Clock Pulse Input |
| D0-D7 | Data Inputs |
| O0-O7 | 3-State Outputs |

ORDERING INFORMATION
See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.


Figure 1. Logic Diagram

| INPUTS |  |  | OUTPUTS | OPERATING MODE |
| :---: | :---: | :---: | :---: | :---: |
| OE | CP | Dn | On |  |
| ${ }_{\text {L }}$ | $\uparrow$ | I | L H | Load and Read Register |
| L | $\uparrow$ | X | NC | Hold and Read Register |
| H | $\uparrow$ | X | Z | Hold and Disable Outputs |
| $\begin{aligned} & \mathrm{H} \\ & \mathrm{H} \end{aligned}$ | $\uparrow$ | I | Z | Load Internal Register and Disable Outputs |

$\mathrm{H}=$ High Voltage Level; $\mathrm{h}=$ High Voltage Level One Setup Time Prior to the Low-to-High Clock Transition; L = Low Voltage Level; I = Low Voltage Level One Setup Time Prior to the Low-to-High Clock Transition; NC = No Change, State Prior to Low-to-High Clock Transition; X = High or Low Voltage Level and Transitions are Acceptable; Z = High Impedance State; $\uparrow=$ Low-to-High Transition; $\uparrow=$ Not a Low-to-High Transition; For Icc Reasons DO NOT FLOAT Inputs

## MC74LVX374

MAXIMUM RATINGS

| Symbol | Parameter | Value |  |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | DC Supply Voltage | -0.5 to +7.0 |  |
| $\mathrm{~V}_{\text {in }}$ | DC Input Voltage | -0.5 to +7.0 |  |
| $\mathrm{~V}_{\text {out }}$ | DC Output Voltage | -0.5 to $\mathrm{V}_{\mathrm{CC}}+0.5$ | V |
| $\mathrm{I}_{\mathrm{IK}}$ | Input Diode Current | -20 |  |
| $\mathrm{I}_{\mathrm{OK}}$ | Output Diode Current | V |  |
| $\mathrm{I}_{\text {out }}$ | DC Output Current, per Pin | $\pm 20$ |  |
| $\mathrm{I}_{\mathrm{CC}}$ | DC Supply Current, $\mathrm{V}_{\mathrm{CC}}$ and GND Pins | mA |  |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation | mA |  |
| $\mathrm{T}_{\text {Stg }}$ | Storage Temperature | m | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {CC }}$ | DC Supply Voltage | 2.0 | 3.6 | V |
| $\mathrm{~V}_{\text {in }}$ | DC Input Voltage | 0 | 5.5 | V |
| $\mathrm{~V}_{\text {out }}$ | DC Output Voltage | 0 | $\mathrm{~V}_{\mathrm{CC}}$ | V |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Temperature, All Package Types | -40 | +85 | ${ }^{\circ} \mathrm{C}$ |
| $\Delta \mathrm{t} / \Delta \mathrm{V}$ | Input Rise and Fall Time | 0 | 100 | $\mathrm{~ns} / \mathrm{V}$ |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | $\underset{\mathrm{VC}}{\mathrm{v}_{\mathrm{cc}}}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}}=-40$ to $85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | High-Level Input Voltage |  | $\begin{aligned} & \hline 2.0 \\ & 3.0 \\ & 3.6 \end{aligned}$ | $\begin{aligned} & \hline 1.5 \\ & 2.0 \\ & 2.4 \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 2.0 \\ & 2.4 \end{aligned}$ |  | V |
| $\mathrm{V}_{\mathrm{IL}}$ | Low-Level Input Voltage |  | $\begin{aligned} & \hline 2.0 \\ & 3.0 \\ & 3.6 \end{aligned}$ |  |  | $\begin{aligned} & 0.5 \\ & 0.8 \\ & 0.8 \end{aligned}$ |  | $\begin{aligned} & 0.5 \\ & 0.8 \\ & 0.8 \end{aligned}$ | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High-Level Output Voltage $\left(\mathrm{V}_{\mathrm{in}}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}}\right)$ | $\begin{aligned} & \mathrm{I}_{\mathrm{OH}}=-50 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{OH}}=-50 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{OH}}=-4 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 3.0 \\ & 3.0 \end{aligned}$ | $\begin{gathered} \hline 1.9 \\ 2.9 \\ 2.58 \end{gathered}$ | $\begin{aligned} & \hline 2.0 \\ & 3.0 \end{aligned}$ |  | $\begin{gathered} \hline 1.9 \\ 2.9 \\ 2.48 \end{gathered}$ |  | V |
| $\mathrm{V}_{\text {OL }}$ | Low-Level Output Voltage $\left(\mathrm{V}_{\text {in }}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}}\right)$ | $\begin{aligned} & \mathrm{IOL}=50 \mu \mathrm{~A} \\ & \mathrm{IOL}=50 \mu \mathrm{~A} \\ & \mathrm{IOL}=4 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & \hline 2.0 \\ & 3.0 \\ & 3.0 \end{aligned}$ |  | $\begin{aligned} & 0.0 \\ & 0.0 \end{aligned}$ | $\begin{gathered} \hline 0.1 \\ 0.1 \\ 0.36 \end{gathered}$ |  | $\begin{gathered} \hline 0.1 \\ 0.1 \\ 0.44 \end{gathered}$ | V |
| 1 in | Input Leakage Current | $\mathrm{V}_{\text {in }}=5.5 \mathrm{~V}$ or GND | 3.6 |  |  | $\pm 0.1$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |
| loz | Maximum 3-State Leakage Current | $\begin{aligned} & \mathrm{V}_{\text {in }}=\mathrm{V}_{\mathrm{IL}} \text { or } \mathrm{V}_{\mathrm{IH}} \\ & \mathrm{~V}_{\text {out }}=\mathrm{V}_{\mathrm{CC}} \text { or } G N D \end{aligned}$ | 3.6 |  |  | $\begin{gathered} \pm 0.2 \\ 5 \end{gathered}$ |  | $\pm 2.5$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{Cc}}$ | Quiescent Supply Current | $\mathrm{V}_{\text {in }}=\mathrm{V}_{\text {cc }}$ or GND | 3.6 |  |  | 4.0 |  | 40.0 | $\mu \mathrm{A}$ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS (Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=3.0 \mathrm{~ns}$ )

| Symbol | Parameter | Test Conditions |  | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max |  |
| ${ }^{\text {max }}$ | Maximum Clock Frequency (50\% Duty Cycle) | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{aligned}$ | $\begin{aligned} & \hline 60 \\ & 45 \end{aligned}$ | $\begin{aligned} & 115 \\ & 60 \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 40 \end{aligned}$ |  | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.3 \pm 0.3 \mathrm{~V}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{aligned}$ | $\begin{aligned} & 100 \\ & 60 \end{aligned}$ | $\begin{gathered} \hline 160 \\ 95 \end{gathered}$ |  | $85$ |  |  |
| $\begin{aligned} & \text { tpLH, } \\ & t_{\text {PHL }} \end{aligned}$ | Propagation Delay CP to O | $\mathrm{V}_{C C}=2.7 \mathrm{~V}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{aligned}$ |  | $\begin{gathered} \hline 8.5 \\ 11.0 \end{gathered}$ | $\begin{aligned} & \hline 16.3 \\ & 19.8 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & 19.5 \\ & 23.0 \end{aligned}$ | ns |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.3 \pm 0.3 \mathrm{~V}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{aligned}$ |  | $\begin{aligned} & 6.7 \\ & 9.2 \end{aligned}$ | $\begin{aligned} & \hline 10.6 \\ & 14.1 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & 12.5 \\ & 16.0 \end{aligned}$ |  |
| $\begin{aligned} & \text { tpzL, } \\ & \text { tpzH } \end{aligned}$ | Output Enable Time OE to O | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \end{aligned}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{aligned}$ |  | $\begin{gathered} \hline 7.6 \\ 10.1 \end{gathered}$ | $\begin{aligned} & \hline 14.5 \\ & 18.0 \end{aligned}$ | $\begin{aligned} & \hline 1.0 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & 17.5 \\ & 210 \end{aligned}$ | ns |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.3 \pm 0.3 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \end{aligned}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{aligned}$ |  | $\begin{aligned} & 5.9 \\ & 8.4 \end{aligned}$ | $\begin{gathered} \hline 9.3 \\ 12.8 \end{gathered}$ | $\begin{aligned} & \hline 1.0 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & 11.0 \\ & 14.5 \end{aligned}$ |  |
| $\begin{aligned} & \text { tpLz, } \\ & \text { tpHZ } \end{aligned}$ | Output Disable Time OE to O | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 11.5 | 18.5 | 1.0 | 22.0 | ns |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=3.3 \pm 0.3 \mathrm{~V} \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | 9.6 | 13.2 | 1.0 | 15.0 |  |
| toshl tosth | Output-to-Output Skew (Note 1) | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=3.3 \pm 0.3 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{aligned}$ |  |  | $\begin{aligned} & 1.5 \\ & 1.5 \end{aligned}$ |  | $\begin{aligned} & 1.5 \\ & 1.5 \end{aligned}$ | ns |

1. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (toshl) or LOW-to-HIGH (tOSLH); parameter guaranteed by design.

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}}=-40$ to $85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Max |  |
| Cin | Input Capacitance |  | 4 | 10 |  | 10 | pF |
| $\mathrm{C}_{\text {out }}$ | Maximum Three-State Output Capacitance |  | 6 |  |  |  | pF |
| $\mathrm{C}_{\text {PD }}$ | Power Dissipation Capacitance (Note 2) |  | 32 |  |  |  | pF |

2. $C_{P D}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $\mathrm{I}_{\mathrm{CC}}(\mathrm{OPR})=\mathrm{C}_{P D} \bullet \mathrm{~V}_{\mathrm{CC}} \bullet \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}} / 8$ (per flip-flop). $\mathrm{C}_{P D}$ is used to determine the no-load dynamic power consumption; $P_{D}=C_{P D} \bullet V_{C C}{ }^{2} \bullet f_{i n}+I_{C C} \bullet V_{C C}$.

NOISE CHARACTERISTICS (Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=3.0 \mathrm{~ns}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$, Measured in SOIC Package)

| Symbol | Characteristic | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: |
|  |  | Typ | Max |  |
| $\mathrm{V}_{\text {OLP }}$ | Quiet Output Maximum Dynamic $\mathrm{V}_{\text {OL }}$ | 0.5 | 0.8 | V |
| Volv | Quiet Output Minimum Dynamic $\mathrm{V}_{\text {OL }}$ | -0.5 | -0.8 | V |
| $\mathrm{V}_{\text {IHD }}$ | Minimum High Level Dynamic Input Voltage |  | 2.0 | V |
| $\mathrm{V}_{\text {ILD }}$ | Maximum Low Level Dynamic Input Voltage |  | 0.8 | V |

TIMING REQUIREMENTS (Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=3.0 \mathrm{~ns}$ )

| Symbol | Parameter | Test Conditions | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\frac{\mathrm{T}_{\mathrm{A}}=-40 \text { to } 85^{\circ} \mathrm{C}}{\text { Limit }}$ | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Typ | Limit |  |  |
| $\mathrm{t}_{\text {w }}$ | Minimum Pulse Width, CP | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=3.3 \pm 0.3 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 7.5 \\ & 5.0 \end{aligned}$ | $\begin{aligned} & 8.0 \\ & 5.5 \end{aligned}$ | ns |
| $\mathrm{t}_{\text {su }}$ | Minimum Setup Time, D to CP | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=3.3 \pm 0.3 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 6.5 \\ & 4.5 \end{aligned}$ | $\begin{aligned} & 6.5 \\ & 4.5 \end{aligned}$ | ns |
| $t_{\text {h }}$ | Minimum Hold Time, D to CP | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=3.3 \pm 0.3 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 2.0 \\ & 2.0 \end{aligned}$ | $\begin{aligned} & \hline 2.0 \\ & 2.0 \end{aligned}$ | ns |

## MC74LVX374

## SWITCHING WAVEFORMS



Figure 2.


Figure 3.


Figure 4.

## TEST CIRCUITS


*Includes all probe and jig capacitance
Figure 5. Propagation Delay Test Circuit

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: |
| MC74LVX374DWR2G | SOIC-20 <br> (Pb-Free) | 1000 Tape \& Reel |
| MC74LVX374DTR2G | TSSOP-20 <br> (Pb-Free) | 2500 Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.


SCALE 1:1


NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES

PER ASME Y14.5M, 1994
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION PROTRUSION. ALLOWABLE PROTRUSION
SHALL BE 0.13 TOTAL IN EXCESS OF B SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS |  |
| :---: | ---: | ---: |
|  | MIN | MAX |
| A | 2.35 | 2.65 |
| A1 | 0.10 | 0.25 |
| b | 0.35 | 0.49 |
| $\mathbf{c}$ | 0.23 | 0.32 |
| D | 12.65 | 12.95 |
| E | 7.40 | 7.60 |
| e | 1.27 BSC |  |
| H | 10.05 | 10.55 |
| $\mathbf{h}$ | 0.25 | 0.75 |
| L | 0.50 | 0.90 |
| $\boldsymbol{\theta}$ | $0^{\circ}$ | $7^{\circ}$ |

GENERIC
MARKING DIAGRAM*


| XXXXX | $=$ Specific Device Code |
| :--- | :--- |
| A | $=$ Assembly Location |
| WL | $=$ Wafer Lot |
| YY | $=$ Year |
| WW | $=$ Work Week |
| G | $=$ Pb-Free Package |

*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-$ Free indicator, " G " or microdot " $\mathrm{\nabla}$ ", may or may not be present.

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| ---: | :--- | :--- | :--- |
| DESCRIPTION: | SOIC-20 WB | PAGE 1 OF 1 |

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TSSOP-20 WB
CASE 948E
ISSUE D
DATE 17 FEB 2016

SCALE 2:1


1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
CONTROLLING DIMENSION: MILLIMETER
2. DIMENSION A DOES NOT INCLUDE MOLD

FLASH, PROTRUSIONS OR GATE BURRS.
FLASH, PROTRUSIONS OR GATE BURRS.
MOLD FLASH OR GATE BURRS SHALL NO
EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE

INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. SHALL NOT EXCEED $0.25(0.010)$ PER SIDE
5. DIMENSION K DOES NOT INCLUDE

DAMBAR PROTRUSION. ALLOWABLE
DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-

|  | MILLIMETERS |  | INCHES |  |
| :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | MAX | MIN | MAX |
| A | 6.40 | 6.60 | 0.252 | 0.260 |
| B | 4.30 | 4.50 | 0.169 | 0.177 |
| C | --- | 1.20 | --- | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 BSC |  | 0.026 BSC |  |
| H | 0.27 | 0.37 | 0.011 | 0.015 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 | BSC | 0.252 BSC |  |
| M | 0 | $0^{\circ}$ | $8^{\circ}$ | 0 |

GENERIC MARKING DIAGRAM* НРННННННН

|  | XXXX |
| :---: | :---: |
|  | XXXX |
|  | ALYW. |
| $\bigcirc$ | - |

A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

- = Pb-Free Package
(Note: Microdot may be in either location)
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-$ Free indicator, " G " or microdot " $\mathrm{\nabla}$ ", may or may not be present.
DIMENSIONS: MILLIMETERS

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| ---: | :--- | :--- | :--- |
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